

MCT

MOS CONTROLLED THYRISTOR

MCT-3600V-M



● 材质/Material

主体/Body: PPS+gf30 (Black)

接触/Contact: BeCu

镀覆/Plating: Au plating (Ni-base)

● 电特性/Electrical Characteristics

额定电流/Rated Current: 1A

绝缘电阻/Insulation Resistance: 1000mΩ min. at 500V DC

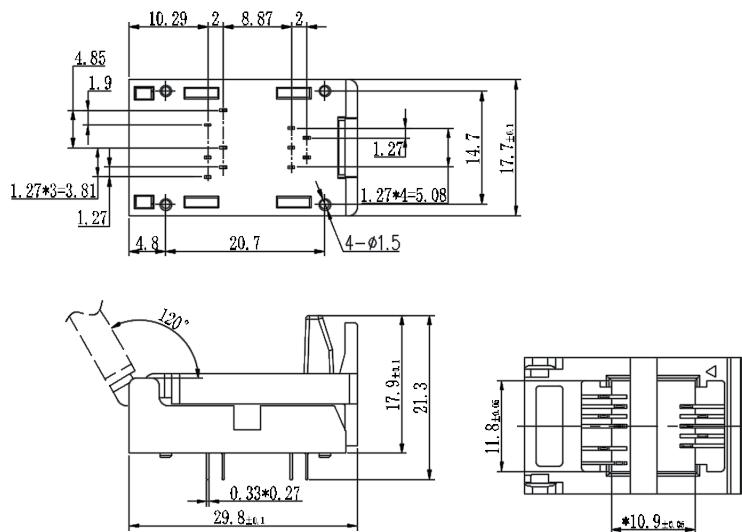
接触电阻/Contact Resistance: 100mΩ max. at 100mA max

● 其他/Others

使用温度/Operating Temperature Range: -55°C~+175°C

抗疲劳/Anti-Fatigue: 50000 cycle (因测试条件不同结果可能不同/Results may vary depending on test conditions)

产品尺寸/Product Dimensions: (长宽高/LWH, 关键封装尺寸/Critical Package Sizes, 引脚尺寸/Pin Size)



器件封装要求含/Device Packaging Requirements Including

